

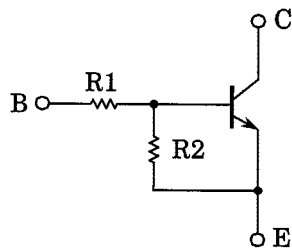
TOSHIBA Transistor Silicon PNP Epitaxial Type (PCT Process)

RN2601,RN2602,RN2603 RN2604,RN2605,RN2606

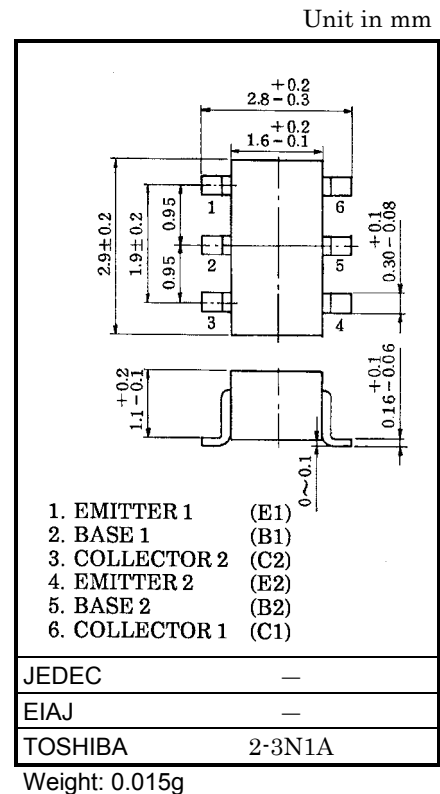
Switching, Inverter Circuit, Interface Circuit
And Driver Circuit Applications

- Including two devices in SM6 (super mini type with 6 leads)
- With built-in bias resistors
- Simplify circuit design
- Reduce a quantity of parts and manufacturing process
- Complementary to RN1601~1606

Equivalent Circuit and Bias Resistor Values



Type No.	R1 (kΩ)	R2 (kΩ)
RN2601	4.7	4.7
RN2602	10	10
RN2603	22	22
RN2604	47	47
RN2605	2.2	47
RN2606	4.7	47

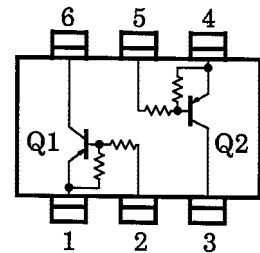


Equivalent Circuit (Top View)

Maximum Ratings (Ta = 25°C) (Q1, Q2 Common)

Characteristic	Symbol	Rating	Unit
Collector-base voltage	V_{CBO}	-50	V
Collector-emitter voltage	V_{CEO}	-50	V
Emitter-base voltage	V_{EBO}	-10	V
		-5	V
Collector current	I_C	-100	mA
Collector power dissipation	P_C^*	300	mW
Junction temperature	T_j	150	°C
Storage temperature range	T_{stg}	-55~150	°C

* Total rating



Electrical Characteristics (Ta = 25°C) (Q1, Q2 common)

Characteristic		Symbol	Test Circuit	Test Condition	Min	Typ.	Max	Unit
Collector cut-off current	RN2601~2606	I_{CBO}	—	$V_{CB} = -50V, I_E = 0$	—	—	-100	nA
		I_{CEO}	—	$V_{CE} = -50V, I_B = 0$	—	—	-500	
Emitter cut-off current	RN2601	I_{EBO}	—	$V_{EB} = -10V, I_C = 0$	-0.82	—	-1.52	mA
	RN2602		—		-0.38	—	-0.71	
	RN2603		—		-0.17	—	-0.33	
	RN2604		—		-0.082	—	-0.15	
	RN2605	I_{EBO}	—	$V_{EB} = -5V, I_C = 0$	-0.078	—	-0.145	
	RN2606		—		-0.074	—	-0.138	
DC current gain	RN2601	h_{FE}	—	$V_{CE} = -5V$ $I_C = -10mA$	30	—	—	—
	RN2602		—		50	—	—	
	RN2603		—		70	—	—	
	RN2604		—		80	—	—	
	RN2605		—		80	—	—	
	RN2606		—		80	—	—	
Collector-emitter saturation voltage	RN2601~2606	$V_{CE(sat)}$	—	$I_C = -5mA$ $I_B = -0.25mA$	—	-0.1	-0.3	V
Input voltage (ON)	RN2601	$V_{I(ON)}$	—	$V_{CE} = -0.2V$ $I_C = -5mA$	-1.1	—	-2.0	V
	RN2602		—		-1.2	—	-2.4	
	RN2603		—		-1.3	—	-3.0	
	RN2604		—		-1.5	—	-5.0	
	RN2605		—		-0.6	—	-1.1	
	RN2606		—		-0.7	—	-1.3	
Input voltage (OFF)	RN2601~2604	$V_{I(OFF)}$	—	$V_{CE} = -5V,$ $I_C = -0.1mA$	-1.0	—	-1.5	V
	RN2605, 2606		—		-0.5	—	-0.8	
Translation frequency	RN2601~2606	f_T	—	$V_{CE} = -10V,$ $I_C = -5mA$	—	200	—	MHz
Collector output capacitance	RN2601~2606	C_{ob}	—	$V_{CB} = -10V, I_E = 0$ $f = 1MHz$	—	3	6	pF
Input resistor	RN2601	R1	—	—	3.29	4.7	6.11	kΩ
	RN2602		—		7	10	13	
	RN2603		—		15.4	22	28.6	
	RN2604		—		32.9	47	61.1	
	RN2605		—		1.54	2.2	2.86	
	RN2606		—		3.29	4.7	6.11	
Resistor ratio	RN2601~2604	R1/R2	—	—	0.9	1.0	1.1	—
	RN2605		—		0.0421	0.0468	0.0515	
	RN2606		—		0.09	0.1	0.11	

(Q1, Q2 Common)

